

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application)	<u>PATENT APPLICATION</u>
)	
Inventor(s):	S. Brad Herner et al.)
)	Art Unit: 1762
Application No.:	10/769,047)
)	Examiner: Bret P. Chen
Filed:	January 30, 2004)
)	
Title:	LOW-TEMPERATURE, LOW-RESISTIVITY, HEAVILY DOPED P-TYPE POLYSILICON DEPOSITION)
)	<u>Customer No. 64948</u>
)	Docket No.: SAND-01138 (MA-100-I)
)	

RESPONSE A TO OFFICE ACTION UNDER 37 C.F.R. § 1.111 TO ACCOMPANY
REQUEST FOR CONTINUED EXAMINATION

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Applicants request continued examination under 37 CFR 1.114. The amended claims and remarks included herein constitute the required submission.

AMENDMENTS to the CLAIMS begin on page 2 of this paper.

REMARKS begin on page 5 of this paper.